

Innovating Photon Detection: Latest Developments in RayQuant's CMOS SiPM Hui Lao RayQuant Technology Co. Ltd. 2024.11.19



Products Outline

02 RQLx035 Product Performance

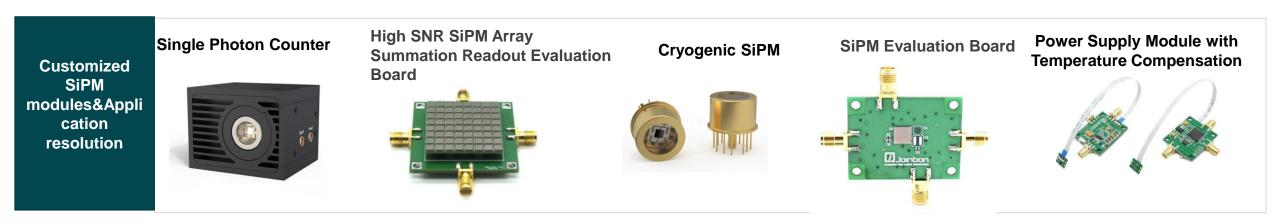


Application Cases



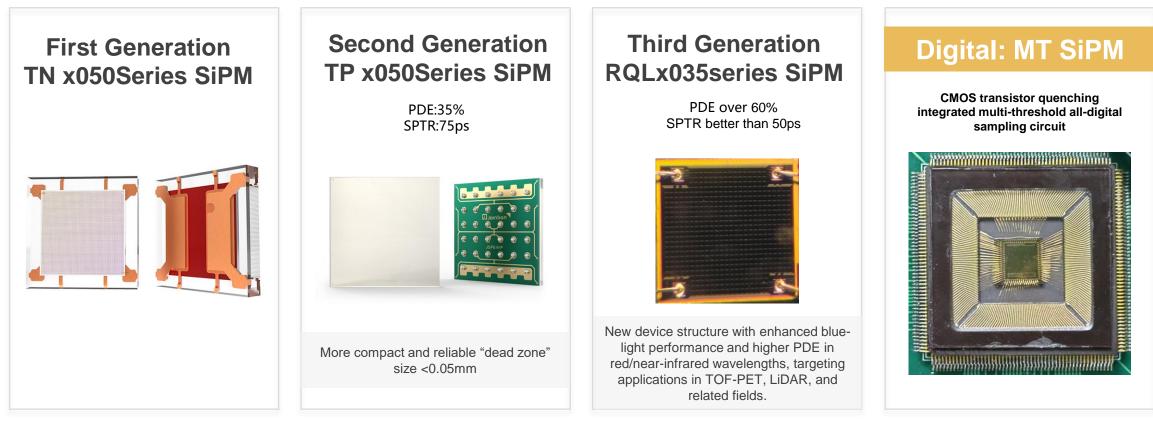
Specializing in SiPM implementation using standard CMOS technology, with developed series of chip products, application modules, and comprehensive solutions.





- RAYQUANT

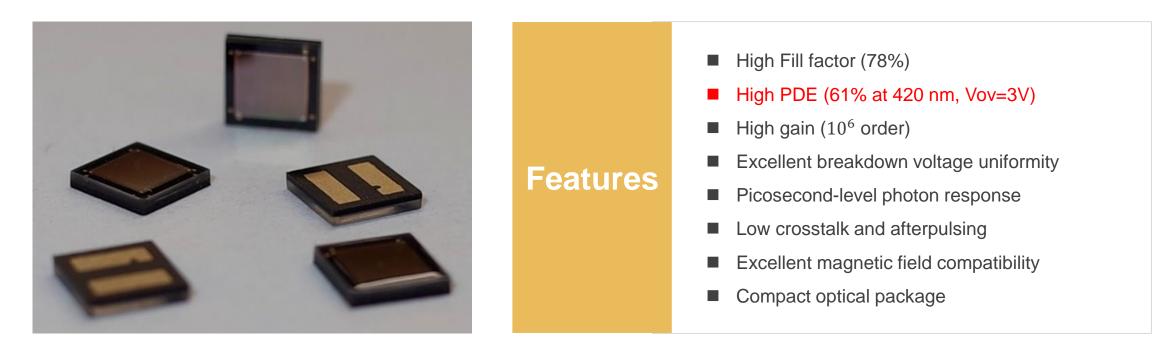
Following three rounds of technological iterations, two generations of SiPM products have been launched and mass-produced.



Nearly 500,000 CMOS SiPM chips have been delivered so far.



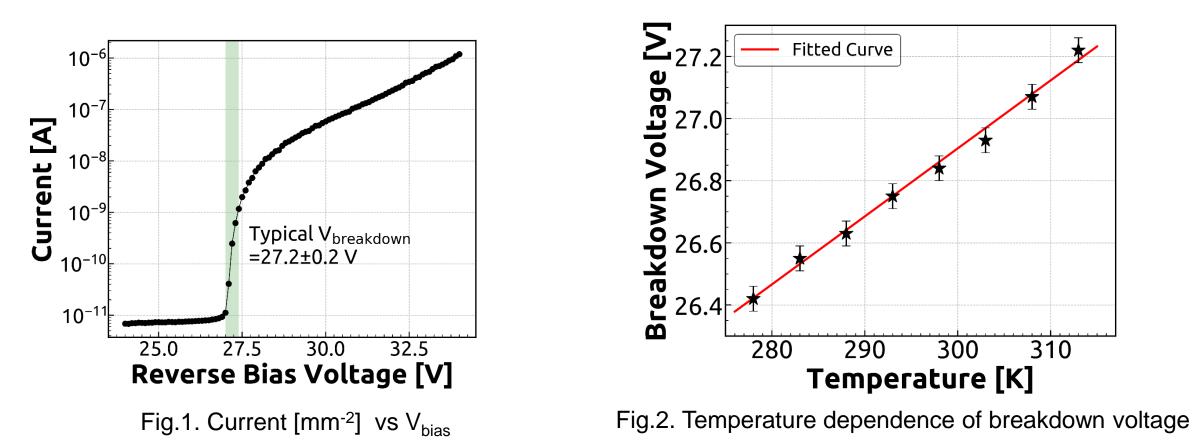
Typ. no.	Active area	Microcell pitch	Number of microcell	Fill Factor
RQL1035	0.98 mm*0.98 mm	25 um	596	78%
RQL3035	2.98 mm*2.98mm	- 35 μm	6501	



RQLx035 Product Performance

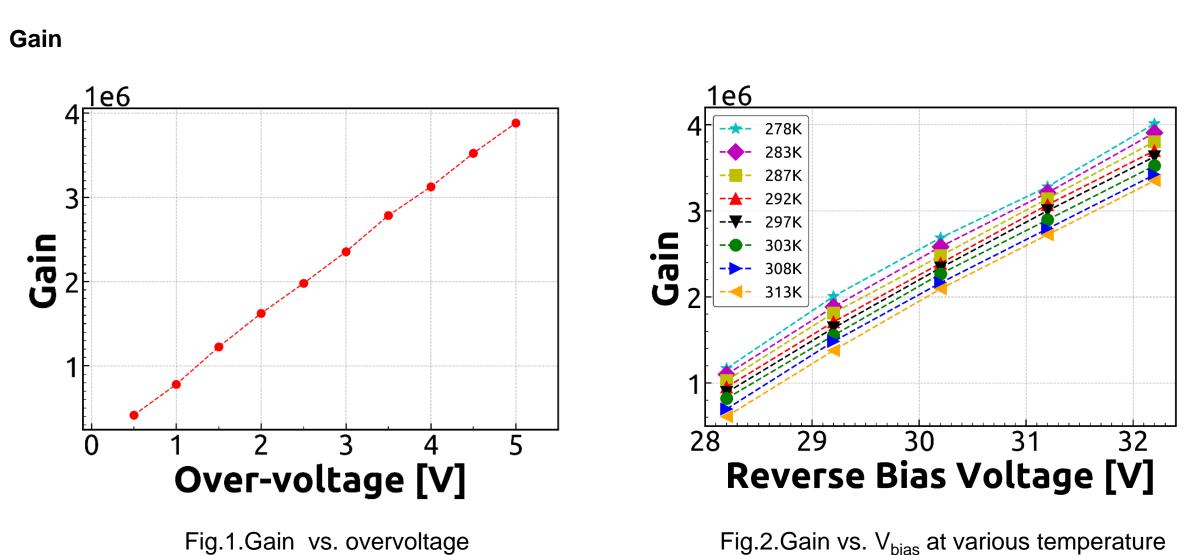
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Breakdown voltage



22mV/K temperature dependence

RQLx035 Product Performance



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Dark count rate (DCR) [mm⁻²] and crosstalk

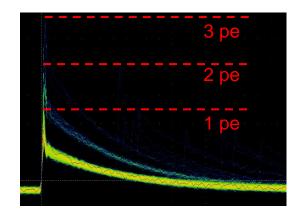
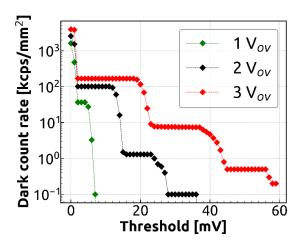


Fig.1. SiPM behavior in dark condition



Dark count rate [kcps/mm²] 50 (2, 100) 00 50 (1, 40) 3 Overvoltage [V] Fig.3. Dark count rate (DCR) [mm⁻²] vs V_{bias} DCR :40 kcps/mm² @ V_{ov}=1V

(3, 170)

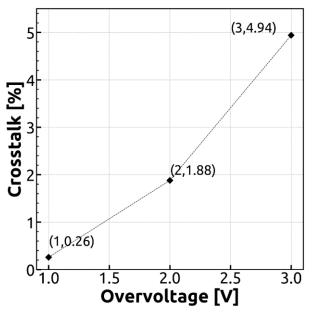


Fig.4.Crosstalk vs V_{bias}

Crosstalk : 0.26% @ V_{ov}=1V

Fig.2. Statistical characteristics

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Photon detection efficiency

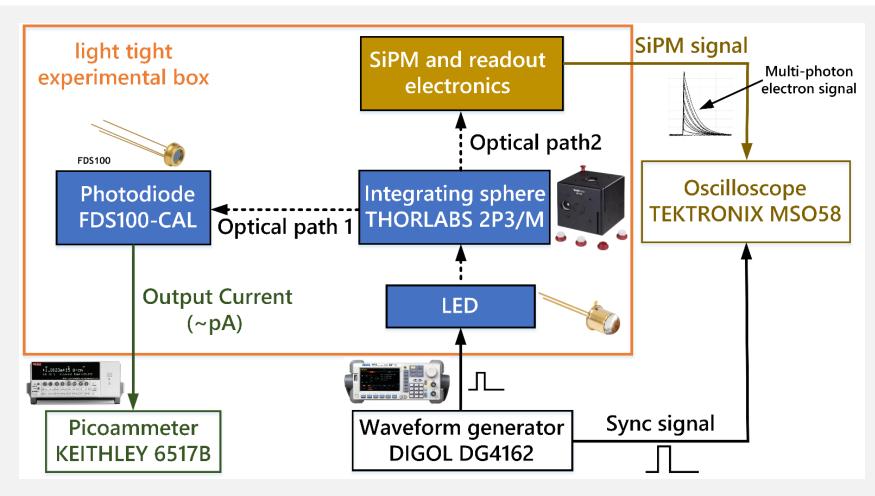
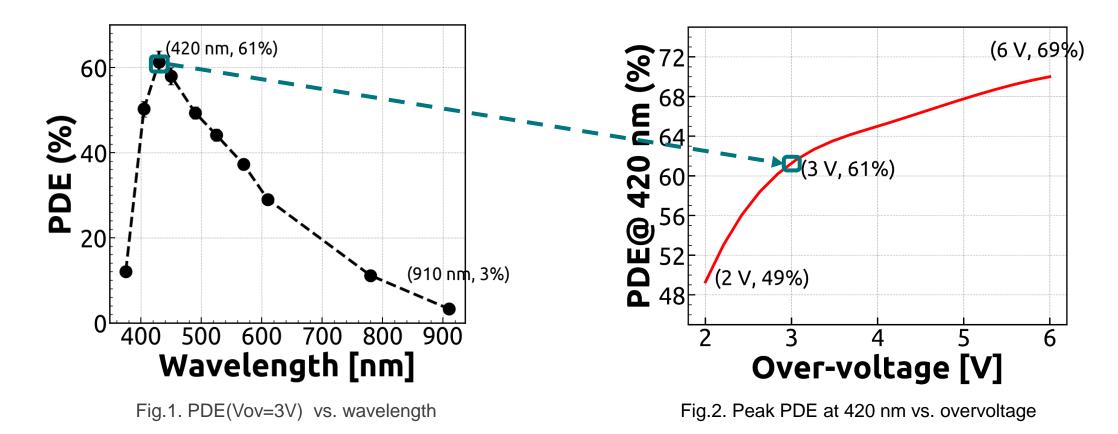


Fig.1. Diagram of PDE measurement setup

RQLx035 Product Performance

Photon detection efficiency



PDE: 69% @ V_{ov}=6V



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Single photon time resolution (SPTR)

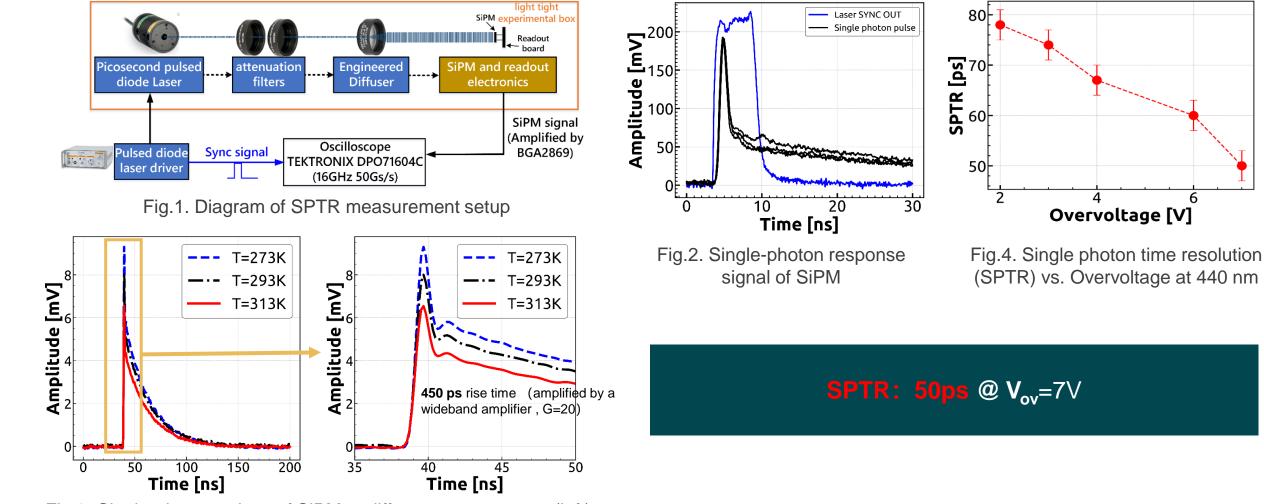


Fig.3. Single-photon pulses of SiPM at different temperatures (left) and zoomed-in view (right)



	TN series	RQL series
V _{breakdown} [V]	25.2 ±0.2V	27.2 ±0.2V
Temperature coefficient of V _{breakdown} [mV/K]	34.4	22.0
Pixel pitch [µm]	50	35
Fill factor	70.6%	78%
C _{pixel} [fF]	165	123
Gain	2.5 × 10 ⁶	1.6 × 10 ⁶
Dark current [nA]	90	35
Dark count rate [kcps/mm ²]	120	100
Optical crosstalk	3.5%	1.88%
Afterpulsing	2.0%	<1%
PDE@420 nm	35%	49%

An excellent CMOS SiPM has been developed at a new generation process:

- More stable temperature characteristics
- Higher fill factor
- Lower dark noise
- Higher PDE

Measured energy resolution (ER)



Energy before correction

Energy after correction

10.6%@511 keV

7.2%@1274.5 keV

3 Vov

4 Vov

5 Vov

6 Vov

7 Vov

8 Vov

ER ∝ — $\sqrt{E_{v}}$

1500

1000

Gaussian fit

• • • Gaussian fit

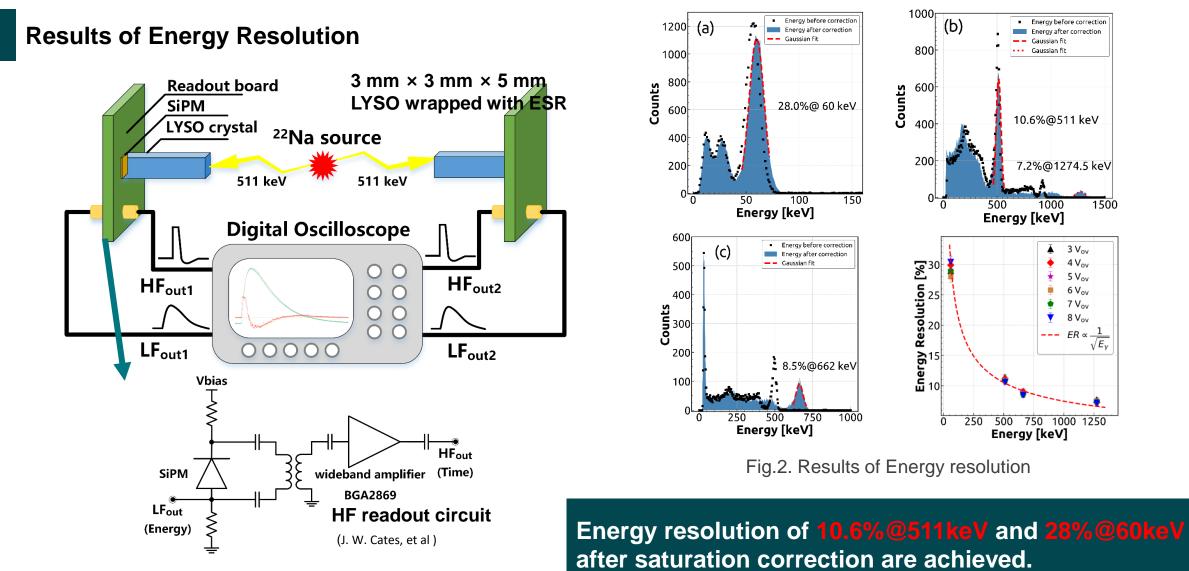
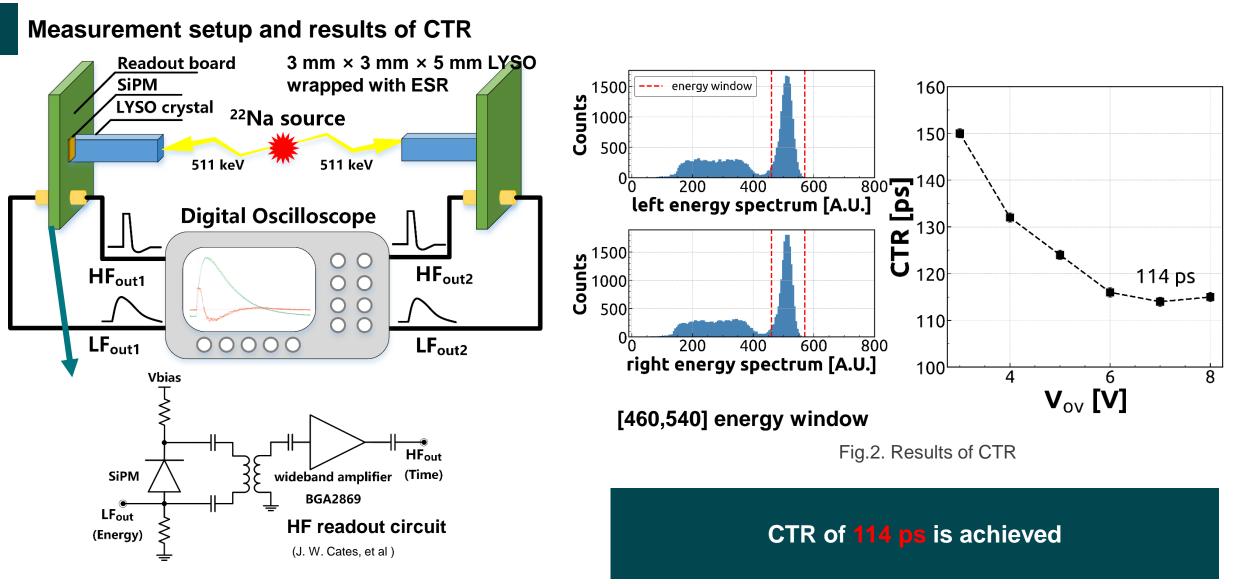


Fig.1. Measurement setup and readout circuit for SiPM

Measured coincidence time resolution (CTR)



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Fig.1. Measurement setup and readout circuit for SiPM



PET is the most advanced medical imaging equipment.

- The most advanced medical imaging technology.
- A molecular imaging technology with extremely high biochemical sensitivity.
- The most comprehensive medical imaging device for localization, qualification, qualification, and monitoring.

TOF (Time of Flight)-
based PET systems have
become feasible.

Significant improvements in spatial resolution, sensitivity, and performance.

Strong magnetic field compatibility (PET-MRI). Radial
Resolution1.9 mm(3D-OSEM)Axial
Resolution1.7 mm(3D-OSEM)Time
Resolution249psEnergy
Resolutions10% @511 keV

17 kcps/MBq

System

Sensitivity

https://www.raysolution.com/

Image courtesy of RAYSOLUTION Healthcare All-digital PET-CT: DigitMI 930

Application Case



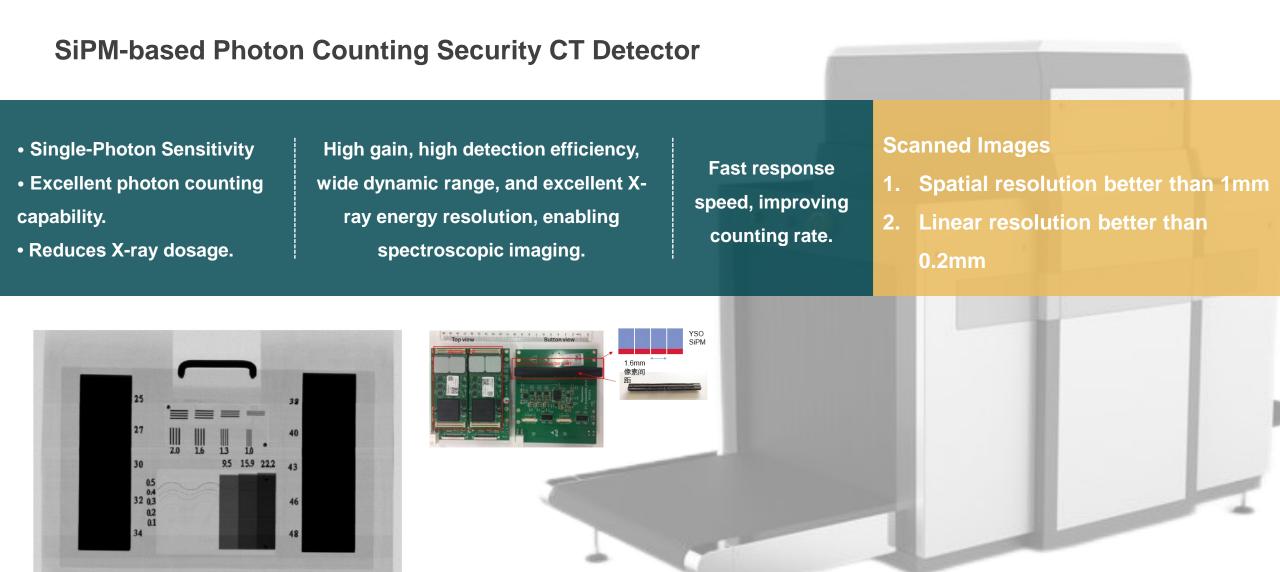
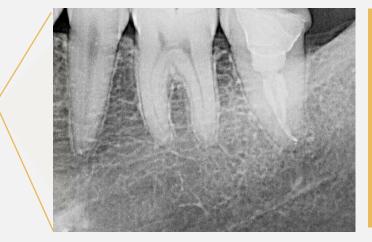


Image courtesy of Raymeasure Technology Co., Ltd. (Suzhou): DexScanner L103

Application Case: Dental CR imaging

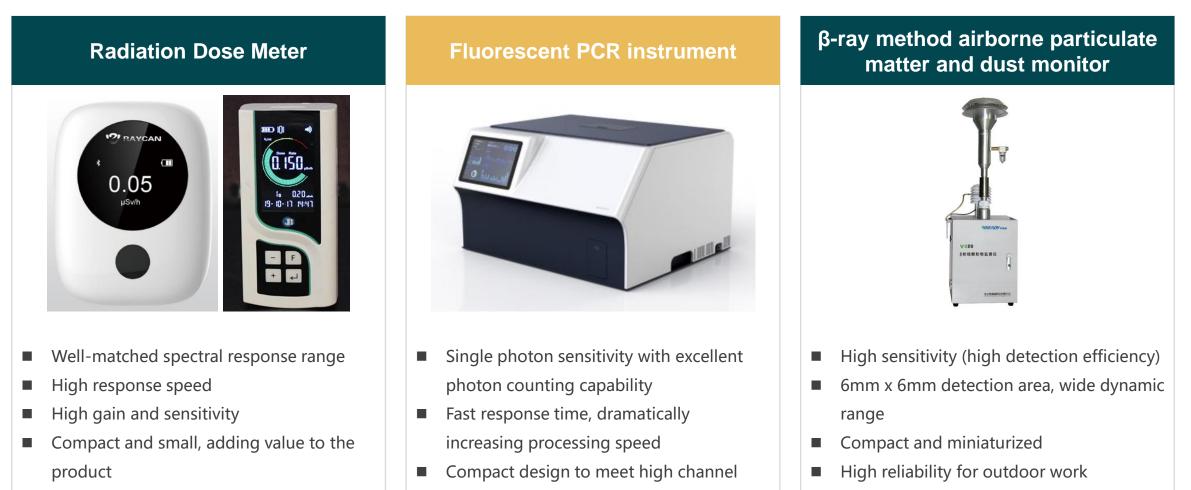






spatial resolution : 17 lp/mm;
imaging time <6s</pre>





density requirements.

Simplifies systems and reduces costs





Thanks !

Hui Lao

RayQuant Technology Co. Ltd. 2024.11.19